

Product Summary

$V_{(BR)DSS}$	$R_{DS(ON)} \text{ max}$	$I_D \text{ max}$ $T_A = +25^\circ\text{C}$
100V	80mΩ @ $V_{GS} = 10\text{V}$	4.2A
	99mΩ @ $V_{GS} = 6.0\text{V}$	3.6A

Description

This MOSFET has been designed to minimize the on-state resistance ($R_{DS(on)}$) and yet maintain superior switching performance, making it ideal for high efficiency power management applications.

Applications

- Power Management Functions
- DC-DC Converters

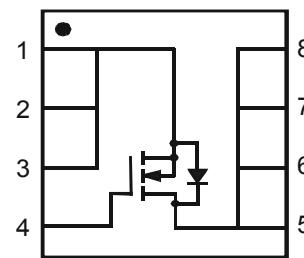
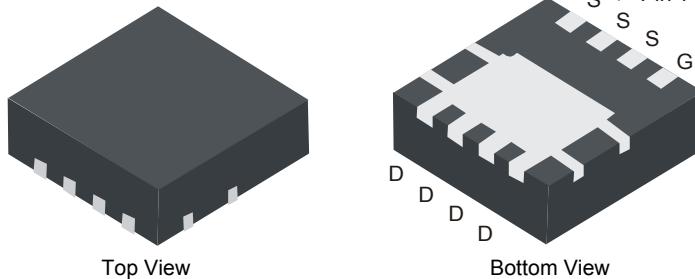
Features and Benefits

- Low $R_{DS(ON)}$ – ensures on state losses are minimized
- Small form factor thermally efficient package enables higher density end products
- Occupies just 33% of the board area occupied by SO-8 enabling smaller end product
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)**
- Halogen and Antimony Free. "Green" Device (Note 3)**
- Qualified to AEC-Q101 Standards for High Reliability**

Mechanical Data

- Case: POWERDI3333-8
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminal Connections Indicator: See diagram
- Terminals: Finish — Matte Tin annealed over Copper leadframe. Solderable per MIL-STD-202, Method 208 (E3)
- Weight: 0.034 grams (approximate)

POWERDI3333-8



Top View
Internal Schematic

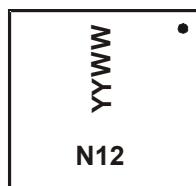
Ordering Information (Note 4)

Part Number	Compliance	Case	Packaging
DMN10H099SFG-7	Standard	POWERDI3333-8	2000/Tape & Reel
DMN10H099SFG-13	Standard	POWERDI3333-8	3000/Tape & Reel

Notes:

- No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.
- See http://www.diodes.com/quality/lead_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- For packaging details, go to our website at <http://www.diodes.com/products/packages.html>

Marking Information



N12 = Product Type Marking Code
 YYWW = Date Code Marking
 YY = Last digit of year (ex: 13 = 2013)
 WW = Week code (01 ~ 53)

Maximum Ratings (@ $T_A = +25^\circ\text{C}$, unless otherwise specified.)

Characteristic			Symbol	Value	Units
Drain-Source Voltage			V_{DSS}	100	V
Gate-Source Voltage			V_{GSS}	± 20	V
Continuous Drain Current (Note 6) $V_{GS} = 10\text{V}$	Steady State	$T_A = +25^\circ\text{C}$ $T_A = +70^\circ\text{C}$	I_D	4.2 3.3	A
	$t < 10\text{s}$	$T_A = +25^\circ\text{C}$ $T_A = +70^\circ\text{C}$	I_D	5.8 4.5	A
Continuous Drain Current (Note 6) $V_{GS} = 6\text{V}$	Steady State	$T_A = +25^\circ\text{C}$ $T_A = +70^\circ\text{C}$	I_D	3.6 2.9	A
	$t < 10\text{s}$	$T_A = +25^\circ\text{C}$ $T_A = +70^\circ\text{C}$	I_D	5.2 4.1	A
Pulsed Drain Current (10 μs pulse, duty cycle = 1%)			I_{DM}	20	A

Thermal Characteristics (@ $T_A = +25^\circ\text{C}$, unless otherwise specified.)

Characteristic			Symbol	Value	Units
Total Power Dissipation (Note 5)	$T_A = +25^\circ\text{C}$		P_D	0.98	W
	$T_A = +70^\circ\text{C}$			0.57	
Thermal Resistance, Junction to Ambient (Note 5)	Steady state		$R_{\theta JA}$	131	°C/W
	$t < 10\text{s}$			76	
Total Power Dissipation (Note 6)	$T_A = +25^\circ\text{C}$		P_D	2.31	W
	$T_A = +70^\circ\text{C}$			1.18	
Thermal Resistance, Junction to Ambient (Note 6)	Steady state		$R_{\theta JA}$	55	°C/W
	$t < 10\text{s}$			28	
Thermal Resistance, Junction to Case (Note 6)			$R_{\theta JC}$	6.9	
Operating and Storage Temperature Range			T_J, T_{STG}	-55 to +150	°C

Electrical Characteristics (@ $T_A = +25^\circ\text{C}$, unless otherwise specified.)

Characteristic	Symbol	Min	Typ	Max	Unit	Test Condition
OFF CHARACTERISTICS (Note 7)						
Drain-Source Breakdown Voltage	BV_{DSS}	100	-	-	V	$V_{GS} = 0\text{V}, I_D = 250\mu\text{A}$
Zero Gate Voltage Drain Current	I_{DSS}	-	-	1.0	μA	$V_{DS} = 80\text{V}, V_{GS} = 0\text{V}$
Gate-Source Leakage	I_{GSS}	-	-	± 100	nA	$V_{GS} = \pm 20\text{V}, V_{DS} = 0\text{V}$
ON CHARACTERISTICS (Note 7)						
Gate Threshold Voltage	$V_{GS(\text{th})}$	1.5	2.0	3.0	V	$V_{DS} = V_{GS}, I_D = 250\mu\text{A}$
Static Drain-Source On-Resistance	$R_{DS(\text{ON})}$	-	54	80	$\text{m}\Omega$	$V_{GS} = 10\text{V}, I_D = 3.3\text{A}$
		-	58	99		$V_{GS} = 6.0\text{V}, I_D = 3.0\text{A}$
Forward Transfer Admittance	$ Y_{fs} $	-	13	-	S	$V_{DS} = 10\text{V}, I_D = 3.3\text{A}$
Diode Forward Voltage	V_{SD}	-	0.77	-	V	$V_{GS} = 0\text{V}, I_S = 3.2\text{A}$
DYNAMIC CHARACTERISTICS (Note 8)						
Input Capacitance	C_{iss}	-	1172	-	pF	$V_{DS} = 50\text{V}, V_{GS} = 0\text{V}, f = 1.0\text{MHz}$
Output Capacitance	C_{oss}	-	40.8	-	pF	
Reverse Transfer Capacitance	C_{rss}	-	31.3	-	pF	
Gate Resistance	R_g	-	1.6	-	Ω	$V_{DS} = 0\text{V}, V_{GS} = 0\text{V}, f = 1.0\text{MHz}$
Total Gate Charge $V_{GS} = 10\text{V}$	Q_g	-	25.2	-	nC	$V_{DS} = 50\text{V}, I_D = 3.3\text{A}$
Total Gate Charge $V_{GS} = 4.5\text{V}$	Q_g	-	12.2	-	nC	
Gate-Source Charge	Q_{gs}	-	5.3	-	nC	
Gate-Drain Charge	Q_{gd}	-	5.9	-	nC	
Turn-On Delay Time	$t_{D(\text{on})}$	-	5.4	-	ns	$V_{GS} = 10\text{V}, V_{DS} = 50\text{V}, R_G = 6.0\Omega, I_D = 3.3\text{A}$
Turn-On Rise Time	t_r	-	5.9	-	ns	
Turn-Off Delay Time	$t_{D(\text{off})}$	-	20.0	-	ns	
Turn-Off Fall Time	t_f	-	7.3	-	ns	

Notes: 5. Device mounted on FR-4 substrate PC board, 2oz copper, with minimum recommended pad layout.

6. Device mounted on FR-4 substrate PC board, 2oz copper, with 1inch square copper plate.

7. Short duration pulse test used to minimize self-heating effect.

8. Guaranteed by design. Not subject to product testing.

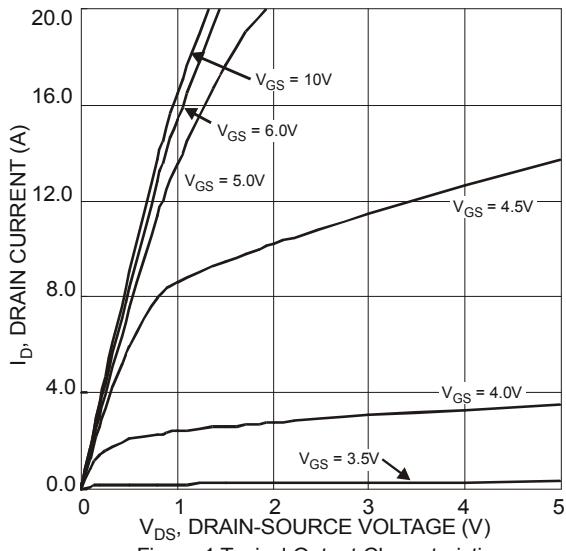


Figure 1 Typical Output Characteristic

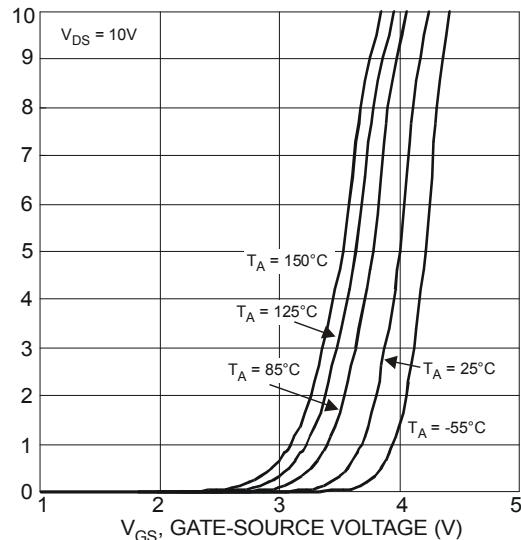


Figure 2 Typical Transfer Characteristics

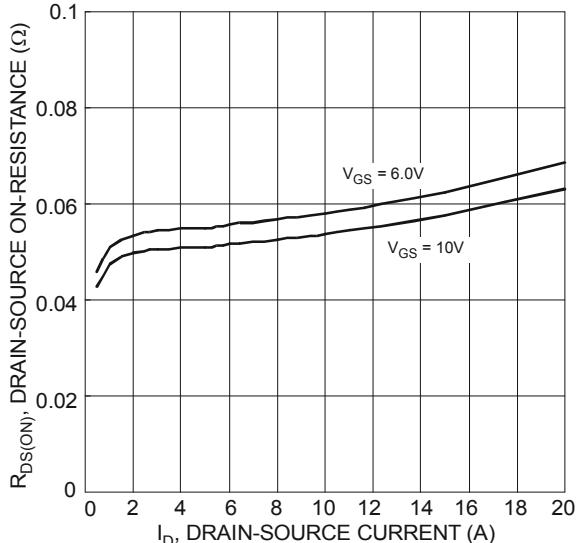


Figure 3 Typical On-Resistance vs.
Drain Current and Gate Voltage

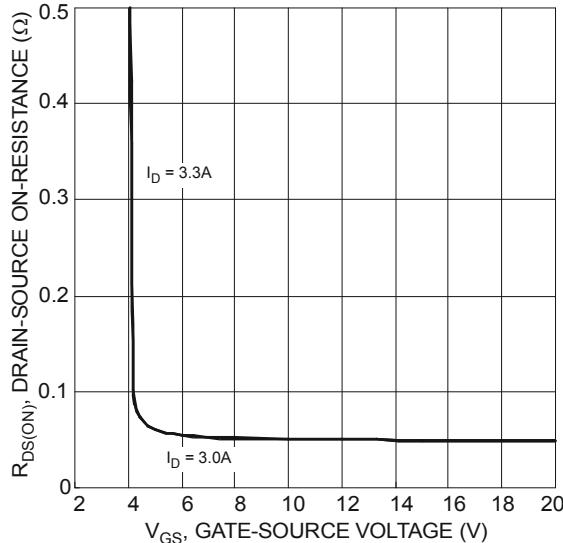


Figure 4 Typical Drain-Source On-Resistance
vs. Gate-Source Voltage

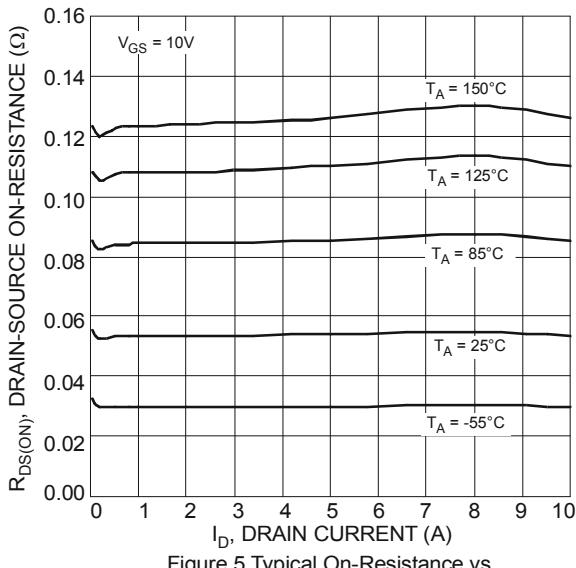


Figure 5 Typical On-Resistance vs.
Drain Current and Temperature

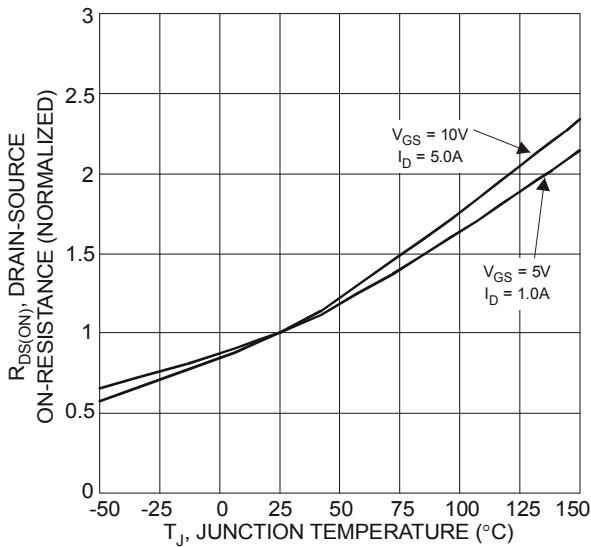
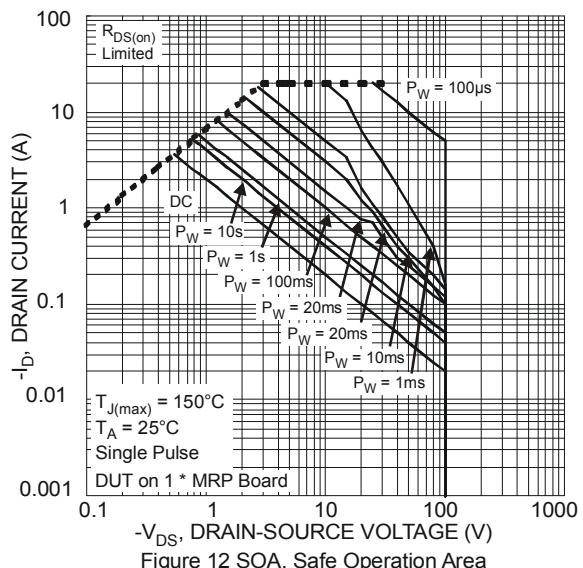
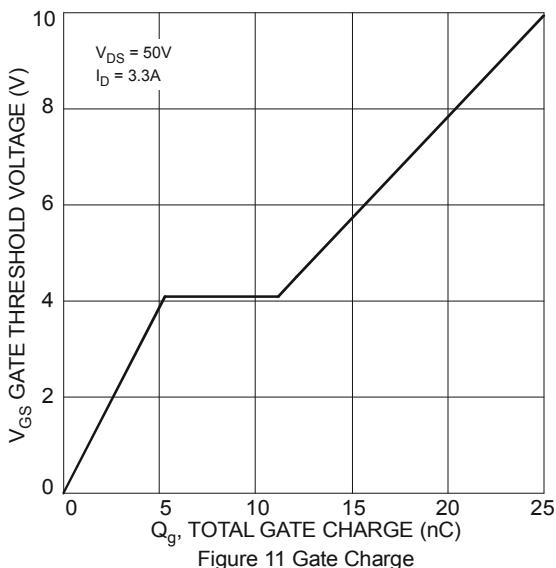
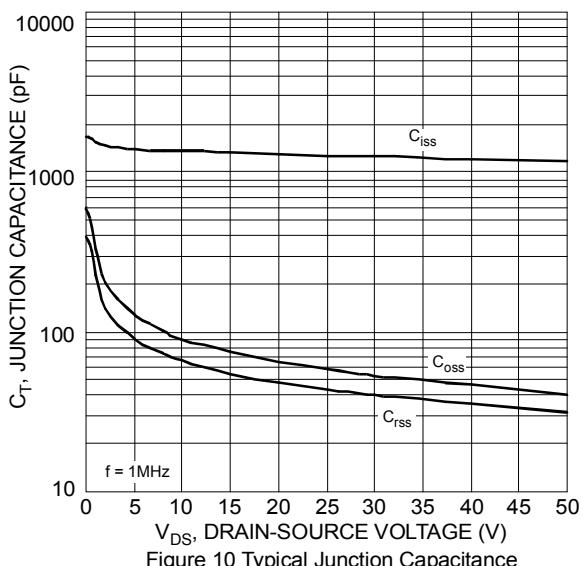
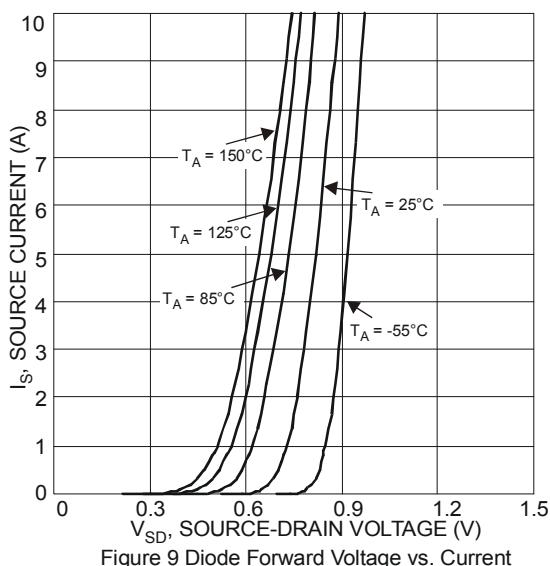
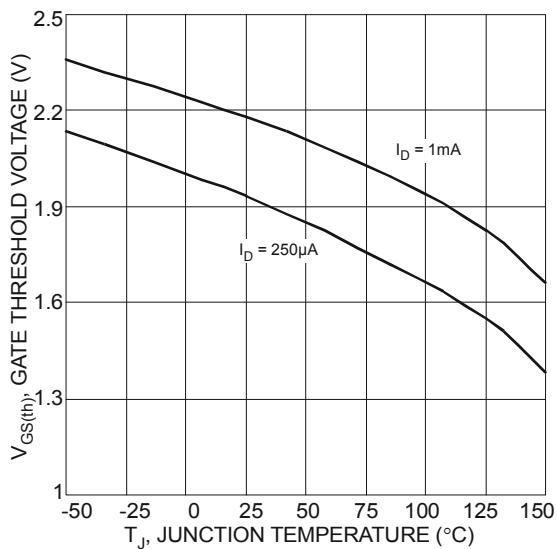
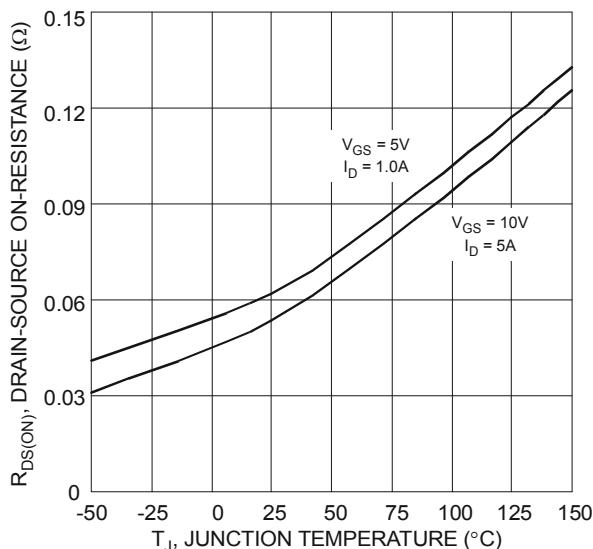
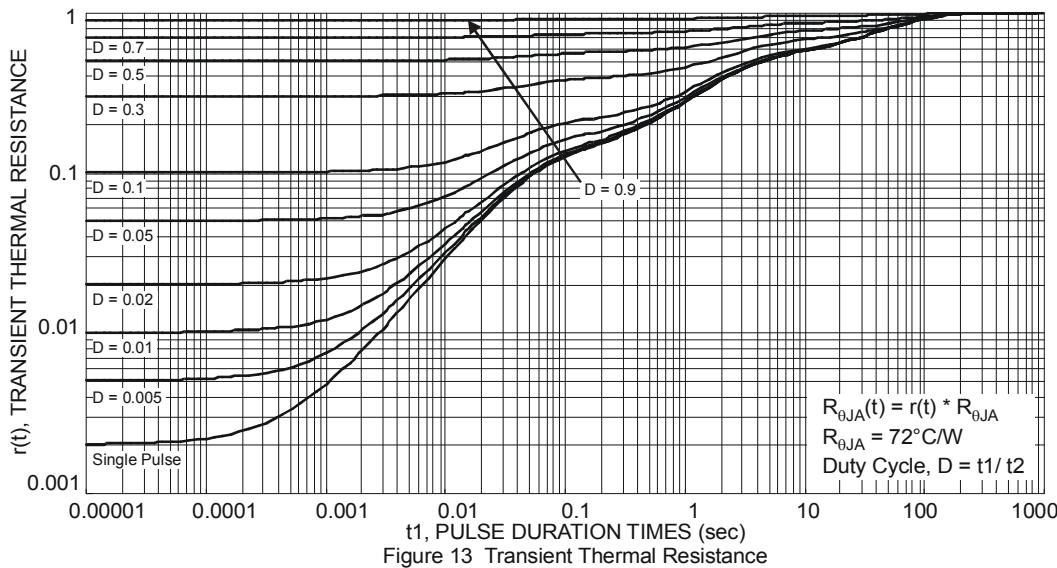


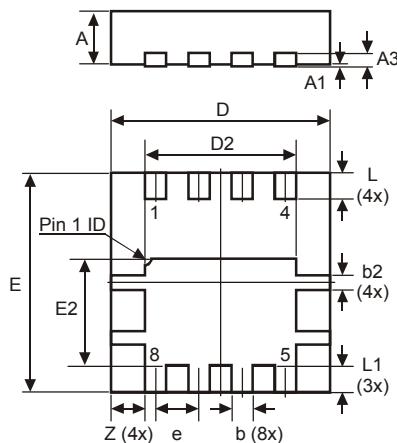
Figure 6 On-Resistance Variation with Temperature





Package Outline Dimensions

Please see AP02002 at <http://www.diodes.com/datasheets/ap02002.pdf> for latest version.

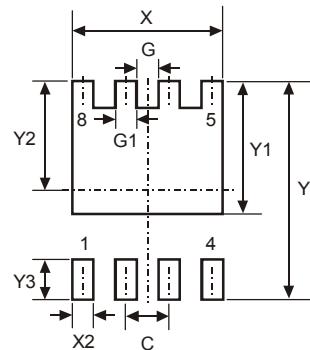


POWERDI3333-8			
Dim	Min	Max	Typ
D	3.25	3.35	3.30
E	3.25	3.35	3.30
D2	2.22	2.32	2.27
E2	1.56	1.66	1.61
A	0.75	0.85	0.80
A1	0	0.05	0.02
A3	—	—	0.203
b	0.27	0.37	0.32
b2	—	—	0.20
L	0.35	0.45	0.40
L1	—	—	0.39
e	—	—	0.65
Z	—	—	0.515

All Dimensions in mm

Suggested Pad Layout

Please see AP02001 at <http://www.diodes.com/datasheets/ap02001.pdf> for latest version.



Dimensions	Value (in mm)
C	0.650
G	0.230
G1	0.420
Y	3.700
Y1	2.250
Y2	1.850
Y3	0.700
X	2.370
X2	0.420

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